



SEMICONDUCTOR

**16CTQ...
16CTQ...S
16CTQ...-1**

**TECHNICAL DATA
DATA SHEET**

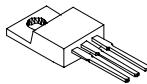
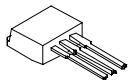
**16CTQ.../16CTQ...S/16CTQ...-1
SCHOTTKY RECTIFIER**

Applications:

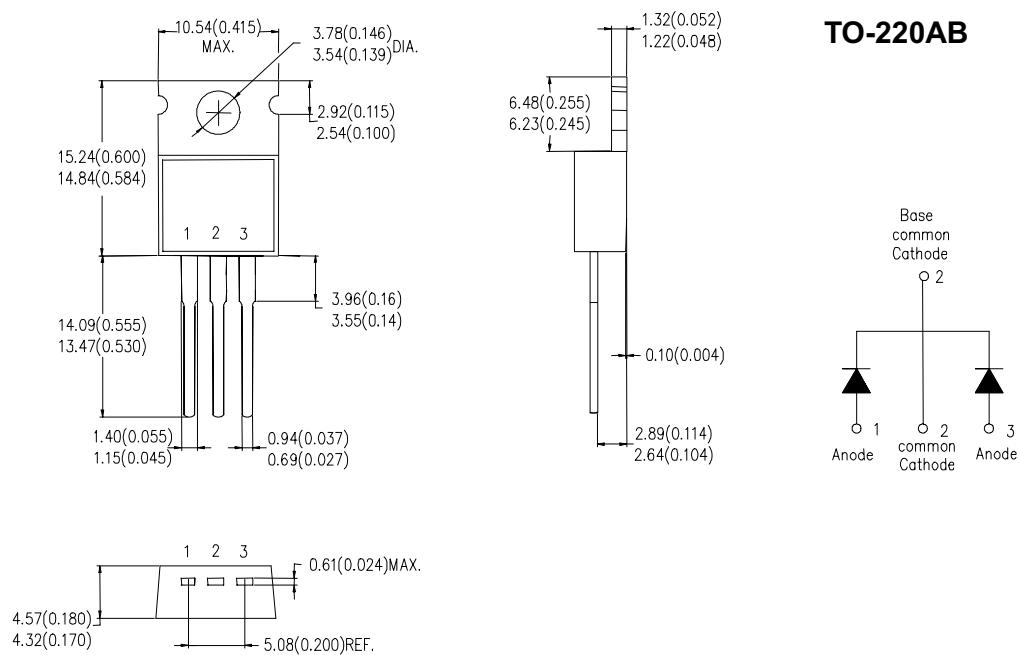
- Switching power supply • Converters • Free-Wheeling diodes • Reverse battery protection

Features:

- 175°C T_J operation
- Center tap TO-220 package
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability

Case Styles		
16CTQ...  TO-220	16CTQ...S  D²PAK	16CTQ...-1  TO-262

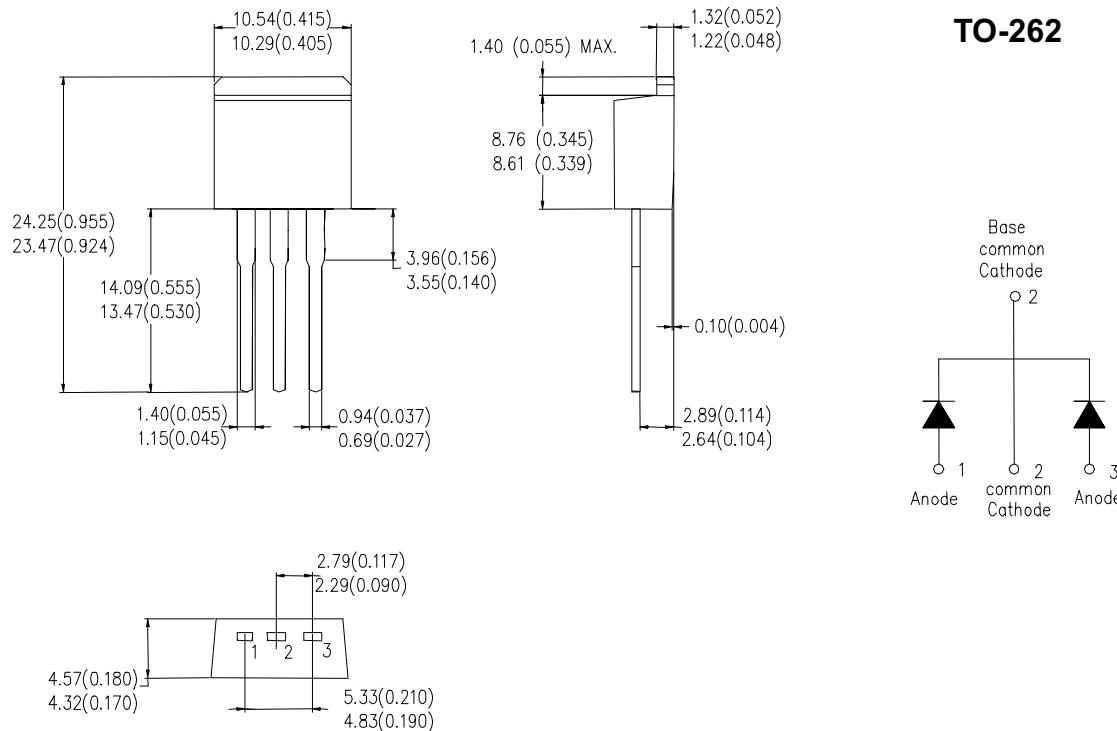
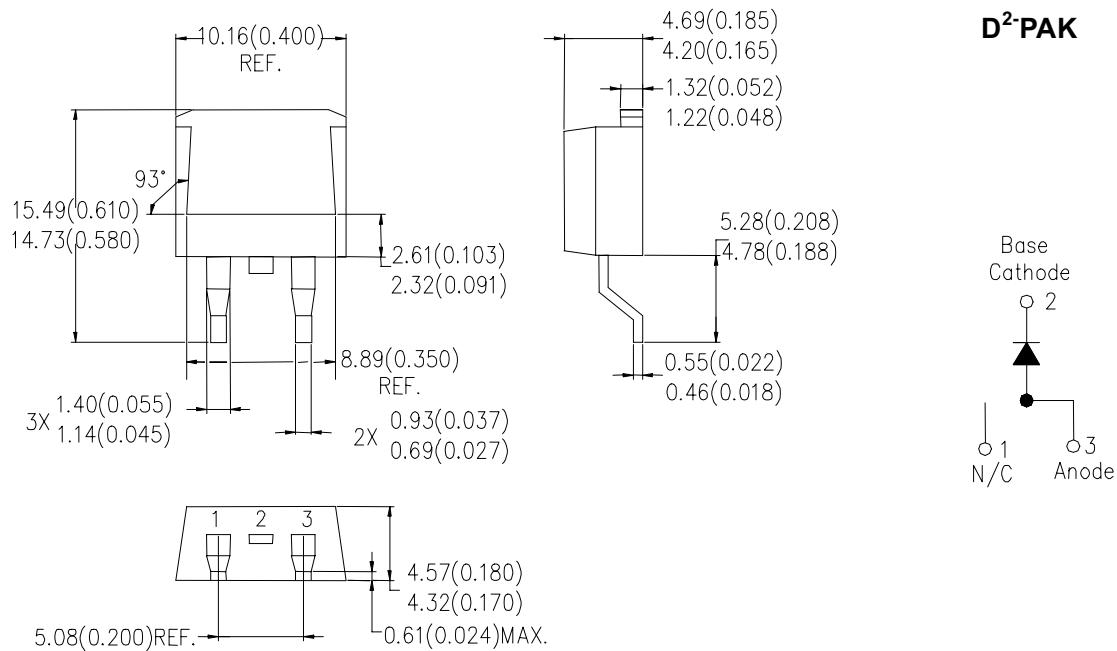
Mechanical Dimensions: In Inches / mm





SEMICONDUCTOR

16CTQ...
16CTQ...S
16CTQ...-1





SEMICONDUCTOR

16CTQ...
16CTQ...S
16CTQ...-1

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	60(16CTQ060.) 80(16CTQ080.) 100(16CTQ100.)	V
Max. Average Forward Current	$I_{F(AV)}$	50% duty cycle @ $T_c = 148^\circ C$, rectangular wave form	8(per leg)	A
			16(Per Device)	
Max. Peak One Cycle Non-Repetitive Surge Current (per leg)	I_{FSM}	8.3 ms, half Sine pulse	330	A
Non-Repetitive Avalanche Energy (per leg)	E_{AS}	$T_J = 25^\circ C$, $I_{AS} = 0.50A$, $L = 60\text{ mH}$	7.50	mJ
Repetitive Avalanche Current (per leg)	I_{AR}	Current decaying linearly to zero in 1 μsec Frequency limited by T_J max. $V_A = 1.5 \times V_R$ typical	0.50	A

Electrical Characteristics:

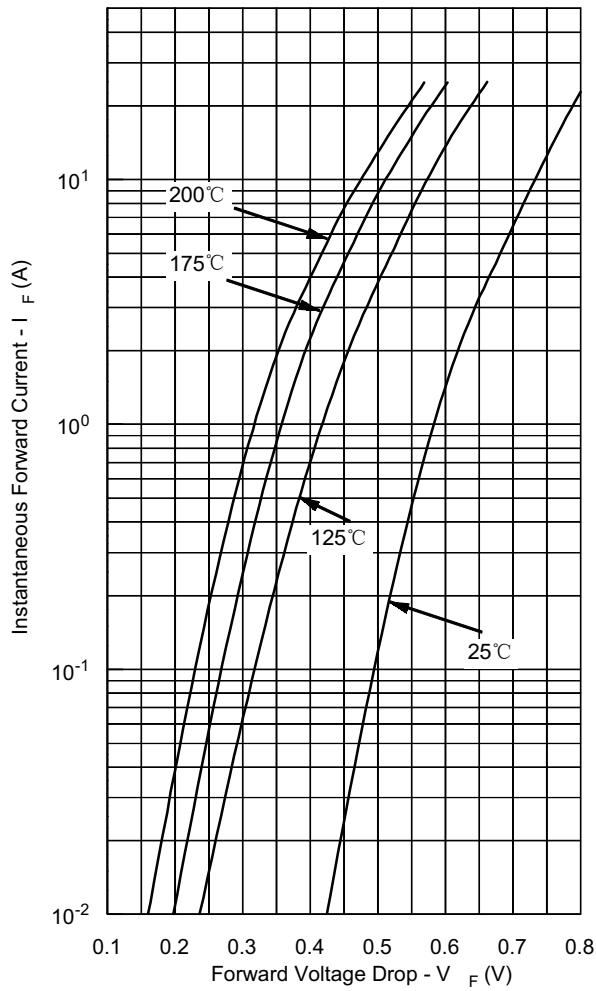
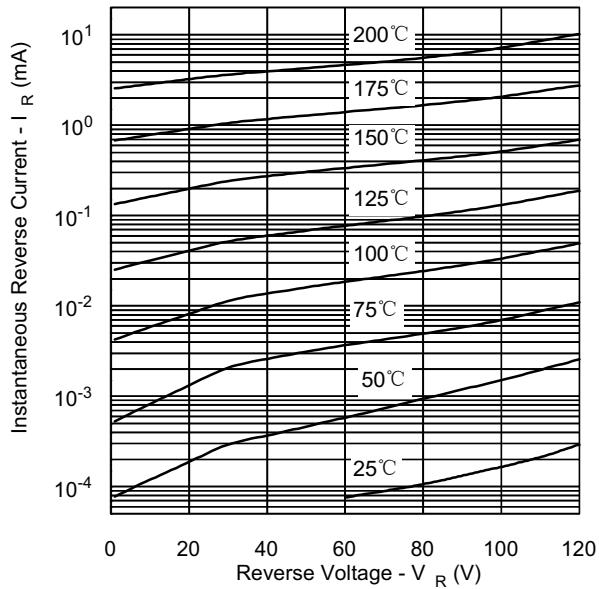
Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop (per leg)*	V_{F1}	@ 8A, Pulse, $T_J = 25^\circ C$ @16 A, Pulse, $T_J = 25^\circ C$	0.72 0.88	V
	V_{F2}	@ 8A, Pulse, $T_J = 125^\circ C$ @ 16 A, Pulse, $T_J = 125^\circ C$	0.58 0.69	V
Max. Reverse Current (per leg)*	I_{R1}	@ V_R = rated V_R $T_J = 25^\circ C$	0.55	mA
	I_{R2}	@ V_R = rated V_R $T_J = 125^\circ C$	7.0	mA
Max. Junction Capacitance (per leg)	C_T	@ $V_R = 5V$, $T_C = 25^\circ C$ $f_{SIG} = 1\text{MHz}$	500	pF
Typical Series Inductance (per leg)	L_S	Measured lead to lead 5 mm from package body	8.0	nH
Max. Voltage Rate of Change	dv/dt	-	10,000	V/ μ s

* Pulse Width < 300 μ s, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	T_J	-	-55 to +175	°C
Max. Storage Temperature	T_{stg}	-	-55 to +175	°C
Maximum Thermal Resistance Junction to Case (per leg)	$R_{\theta JC}$	DC operation	3.25	°C/W
Maximum Thermal Resistance Junction to Case (per package)	$R_{\theta JC}$	DC operation	1.63	°C/W
Maximum Thermal Resistance, Case to Heat Sink	$R_{\theta CS}$	Mounting surface, smooth and greased	0.50	°C/W
Approximate Weight	wt	-	2.0	g
Mounting Torque	T_M	-	6 (min) 12 (max)	Kg-cm
Case Style	TO-220 D ² PAK TO-262 (Suffix “-1” for TO-262; Suffix “S” for D ² PAK)			

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Typical Forward Characteristics

Typical Reverse Characteristics

Typical Junction Capacitance
